FORM PTO-1449

SEP 1 8 2005

INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional) 81839.0107 Application Number 10/009,910

Applicant

IIDA, et al.

Filing Date December 12, 2001 Group Art Unit 1722

		U.S. PATENT	DOCUMENTS	}			
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